



100V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| V _{(BR)DSS} | R _{DS(ON)} Max | I _D T _C = +25°C |
|----------------------|-------------------------|--|
| 100V | 140mΩ @ $V_{GS} = 10V$ | 12A |
| | 160mΩ @ $V_{GS} = 4.5V$ | 11A |

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}), yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- **DC-DC Converters**
- **Power Management Functions**
- Analog Switch

Features

- Low On-Resistance
- Low Input Capacitance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

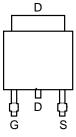
Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.33 grams (Approximate)

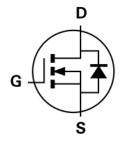
TO252 (DPAK)



Top View



Top View



Internal Schematic

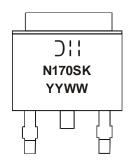
Ordering Information (Note 4)

| Part Number | Case | Packaging | |
|-----------------|--------------|-------------------|--|
| DMN10H170SK3-13 | TO252 (DPAK) | 2,500/Tape & Reel | |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information



☐ I = Manufacturer's Marking N170SK= Product Type Marking Code YYWW = Date Code Marking YY = Last Digit of Year (ex: 15 = 2015)WW=Week Code (01 to 53)



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

| Characteristic | Symbol | Value | Units | | |
|---|------------------|-----------|------------------|-----|----|
| Drain-Source Voltage | V _{DSS} | 100 | V | | |
| Gate-Source Voltage | | | V _{GSS} | ±20 | V |
| Continuous Drain Current (Note 5) V _{GS} = 10V | ID | 12 7.5 | А | | |
| Maximum Body Diode Forward Current (Note 5) | | | Is | 4 | Α |
| Pulsed Drain Current (10µs pulse, duty cycle = 1%) | | | I _{DM} | 16 | Α |
| Avalanche Current (Note 6) | | | I _{AS} | 5.3 | Α |
| Avalanche Energy (Note 6) | | | E _{AS} | 20 | mJ |

Thermal Characteristics

| Characteristic | Symbol | Value | Units | | |
|--|----------------------------------|------------------|-------|------|--|
| Total Dower Discipation (Note 5) | $T_C = +25$ °C | C | 42 | - W | |
| Total Power Dissipation (Note 5) | T _C = +100°C | P_{D} | 17 | | |
| Thermal Resistance, Junction to Ambient (Note 5) | | R _{0JA} | 44 | °C/W | |
| Thermal Resistance, Junction to Case (Note 5) | | R _{0JC} | 3 | C/VV | |
| Operating and Storage Temperature Range | T _{J,} T _{STG} | -55 to +150 | °C | | |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|---------------------|-----|-------|-----|-------|---|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | 100 | _ | _ | V | $V_{GS} = 0V, I_D = 250\mu A$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | _ | _ | 1 | μA | $V_{DS} = 100V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | _ | _ | 100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | 1.0 | 2.0 | 3.0 | V | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | |
| Static Drain-Source On-Resistance | | _ | 99 | 140 | mΩ | $V_{GS} = 10V, I_{D} = 5A$ | |
| Static Drain-Source On-Resistance | R _{DS(ON)} | _ | 104 | 160 | 11122 | $V_{GS} = 4.5V, I_D = 5A$ | |
| Diode Forward Voltage | V_{SD} | _ | 0.7 | 1.0 | V | $V_{GS} = 0V, I_{S} = 10A$ | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | | |
| Input Capacitance | C _{iss} | _ | 1,167 | _ | | V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz | |
| Output Capacitance | Coss | _ | 36 | | pF | | |
| Reverse Transfer Capacitance | Crss | _ | 25 | _ | | | |
| Gate Resistance | R_{G} | _ | 1.3 | _ | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$ | |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | _ | 4.9 | _ | | | |
| Total Gate Charge (V _{GS} = 10V) | Q_g | _ | 9.7 | _ | nC | $V_{DS} = 80V, I_D = 12.8A$ | |
| Gate-Source Charge | Q_{gs} | _ | 2.0 | _ | IIC | | |
| Gate-Drain Charge | Q_{gd} | _ | 2.0 | _ | | | |
| Turn-On Delay Time | t _{D(on)} | _ | 10.5 | _ | | | |
| Turn-On Rise Time | t _r | _ | 11.1 | _ | nS | $V_{DD} = 50V$, $R_G = 25\Omega$, $I_D = 12.8A$ | |
| Turn-Off Delay Time | t _{D(off)} | _ | 42.6 | _ | 113 | | |
| Turn-Off Fall Time | t _f | _ | 12.8 | _ | | | |
| Body Diode Reverse Recovery Time | t _{rr} | _ | 30.3 | _ | nS | $V_{GS} = 0V$, $I_{S} = 12.8A$, $dI/dt = 100A/\mu s$ | |
| Body Diode Reverse Recovery Charge | Q _{rr} | _ | 35.2 | _ | nC | $V_{GS} = 0V$, $I_S = 12.8A$, $dI/dt = 100A/\mu s$ | |

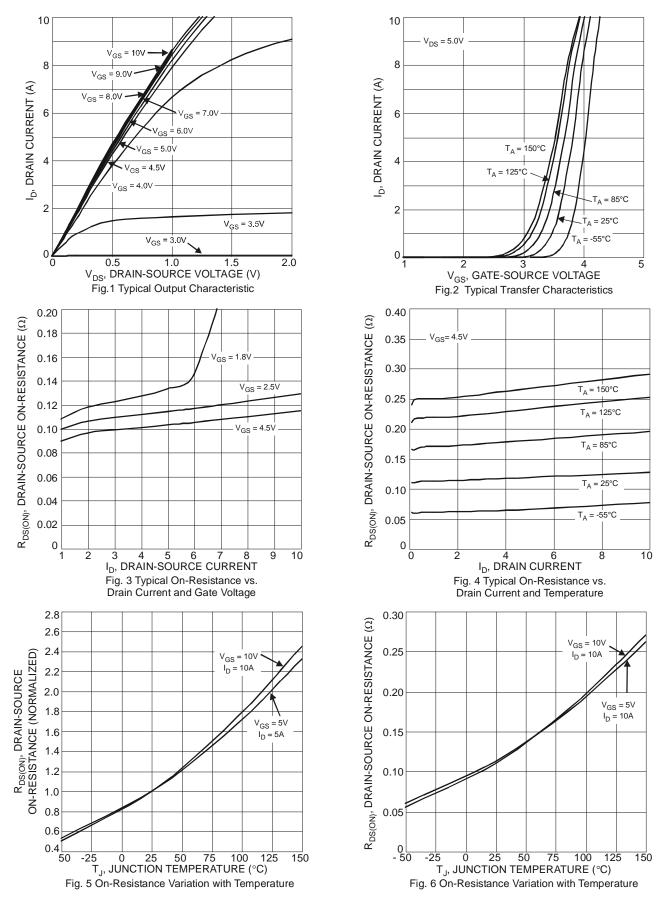
Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper pad layout.

^{6.} UIS in production with L = 1.43mH, $T_J = +25$ °C.

^{7.} Short duration pulse test used to minimize self-heating effect.

^{8.} Guaranteed by design; not subject to production testing.







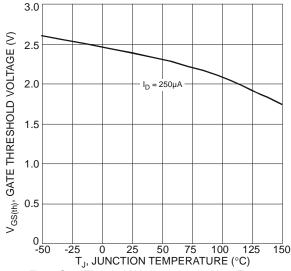


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

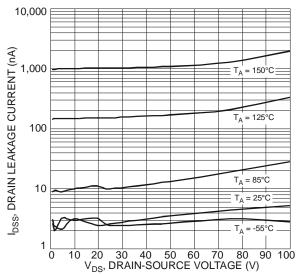
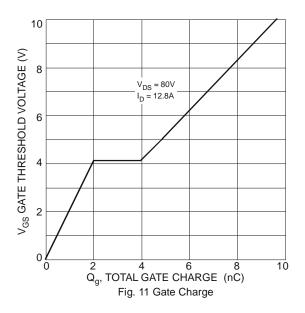
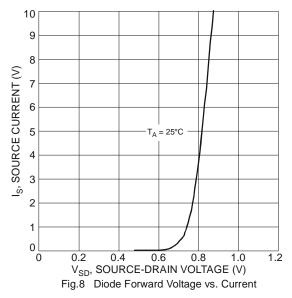
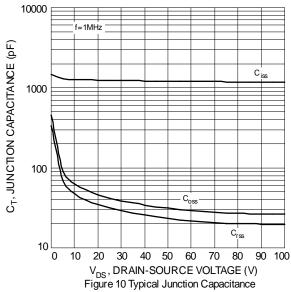
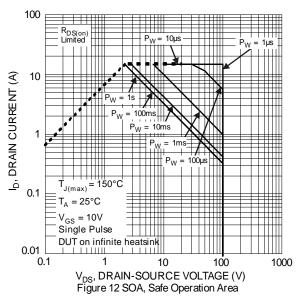


Fig. 9 Typical Drain-Source Leakage Current vs. Voltage

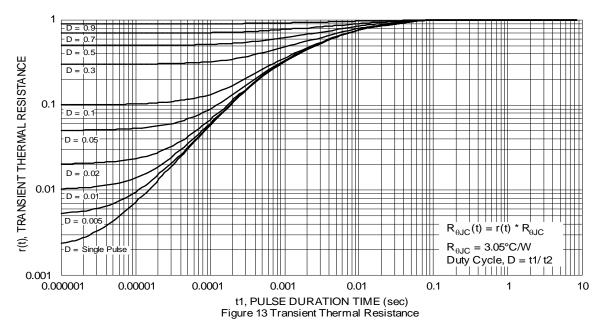










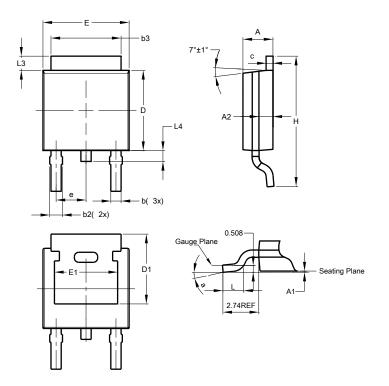




Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

TO252 (DPAK)

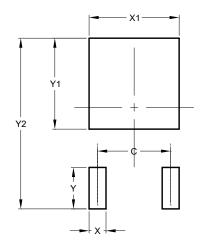


| TO252 (DPAK) | | | | |
|----------------------|------|-------|-------|--|
| Dim | Min | Max | Тур | |
| Α | 2.19 | 2.39 | 2.29 | |
| A1 | 0.00 | 0.13 | 0.08 | |
| A2 | 0.97 | 1.17 | 1.07 | |
| b | 0.64 | 0.88 | 0.783 | |
| b2 | 0.76 | 1.14 | 0.95 | |
| b3 | 5.21 | 5.46 | 5.33 | |
| С | 0.45 | 0.58 | 0.531 | |
| D | 6.00 | 6.20 | 6.10 | |
| D1 | 5.21 | - | - | |
| е | - | - | 2.286 | |
| Е | 6.45 | 6.70 | 6.58 | |
| E1 | 4.32 | - | - | |
| Н | 9.40 | 10.41 | 9.91 | |
| L | 1.40 | 1.78 | 1.59 | |
| L3 | 0.88 | 1.27 | 1.08 | |
| L4 | 0.64 | 1.02 | 0.83 | |
| а | 0° | 10° | - | |
| All Dimensions in mm | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

TO252 (DPAK)



| Dimensions | Value (in mm) | | | |
|------------|---------------|--|--|--|
| С | 4.572 | | | |
| Х | 1.060 | | | |
| X1 | 5.632 | | | |
| Υ | 2.600 | | | |
| Y1 | 5.700 | | | |
| Y2 | 10.700 | | | |



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